Product data sheet

1. General description

PNP Darlington transistor in a SOT89 (SC-62) flat lead Surface-Mounted Device (SMD) plastic package.

NPN complement: BST50-Q

2. Features and benefits

- Integrated diode and resistor
- Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

- Industrial switching applications such as:
 - · Print hammer
 - Solenoid
 - · Relay and lamp driving

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base	-	-	-45	V
Ic	collector current		-	-	-1	Α
h _{FE}	DC current gain	V_{CE} = -10 V; I_{C} = -150 mA; pulsed; t_{p} ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	1000	-	-	

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E	emitter		2
2	С	collector		3
3	В	base	3 2 1 SOT89	sym081



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6. Ordering information

Table 3. Ordering information

Type number	ber Package				
	Name	Description	Version		
BST60-Q		plastic, surface-mounted package; 3 leads; 1.5 mm pitch; 4.5 mm x 2.5 mm x 1.5 mm body	SOT89		

7. Marking

Table 4. Marking codes

Type number	Marking code
BST60-Q	BS1

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter		-	-60	V
V _{CEO}	collector-emitter voltage	open base		-	-45	V
V _{EBO}	emitter-base voltage	open collector		-	-5	V
I _C	collector current			-	-1	Α
I _{CM}	peak collector current			-	-2	Α
I _B	base current			-	-100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	1.3	W
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for collector 6 cm².

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	96	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point			-	-	16	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for collector 6 cm².

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10. Characteristics

Table 7. Characteristics

	Conditions		Min	Тур	Max	Unit
emitter-base cut-off current	$V_{EB} = -4 \text{ V}; I_{C} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		-	-	-50	nA
collector-emitter cut-off current	V _{CE} = -45 V; V _{BE} = 0 V; T _{amb} = 25 °C		-	-	-50	nA
DC current gain	V_{CE} = -10 V; I_{C} = -150 mA; pulsed; t_{p} ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C		1000	-	-	
	V_{CE} = -10 V; I_{C} = -500 mA; pulsed; t_{p} ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C		2000	-	-	
collector-emitter saturation voltage	I_C = -500 mA; I_B = -0.5 mA; T_{amb} = 25 °C		-	-	-1.3	V
	I_C = 500 mA; I_B = -0.5 mA; T_j = 150 °C		-	-	-1.3	V
base-emitter saturation voltage	I_C = -500 mA; I_B = -0.5 mA; T_{amb} = 25 °C		-	-	-1.9	V
transition frequency	V_{CE} = -5 V; I_{C} = -500 mA; f = 100 MHz; T_{amb} = 25 °C		-	200	-	MHz
s (between 10% and 90°	% levels)					·
turn-on time	I_{Bon} = -0.5 mA; I_{Boff} = 0.5 mA; I_{Con} =		-	500	-	ns
turn-off time	-500 mA; T _{amb} = 25 °C		-	700	-	ns
	current collector-emitter cut-off current DC current gain collector-emitter saturation voltage base-emitter saturation voltage transition frequency s (between 10% and 90° turn-on time	current collector-emitter cut-off current $V_{CE} = -45 \text{ V}; V_{BE} = 0 \text{ V}; T_{amb} = 25 \text{ °C}$ current $V_{CE} = -10 \text{ V}; I_{C} = -150 \text{ mA}; \text{ pulsed}; t_{p} \leq 300 \text{ µs}; \delta \leq 0.02; T_{amb} = 25 \text{ °C}$ $V_{CE} = -10 \text{ V}; I_{C} = -500 \text{ mA}; \text{ pulsed}; t_{p} \leq 300 \text{ µs}; \delta \leq 0.02; T_{amb} = 25 \text{ °C}$ collector-emitter saturation voltage $I_{C} = -500 \text{ mA}; I_{B} = -0.5 \text{ mA}; T_{amb} = 25 \text{ °C}$ $I_{C} = 500 \text{ mA}; I_{B} = -0.5 \text{ mA}; T_{j} = 150 \text{ °C}$ base-emitter saturation voltage $I_{C} = -500 \text{ mA}; I_{B} = -0.5 \text{ mA}; T_{amb} = 25 \text{ °C}$ transition frequency $V_{CE} = -5 \text{ V}; I_{C} = -500 \text{ mA}; f = 100 \text{ MHz}; T_{amb} = 25 \text{ °C}$ s (between 10% and 90% levels) $I_{Bon} = -0.5 \text{ mA}; I_{Boff} = 0.5 \text{ mA}; I_{Con} = 500 \text{ mA}; T_{con} = 25 \text{ °C}$	current collector-emitter cut-off current $V_{CE} = -45 \text{ V}; V_{BE} = 0 \text{ V}; T_{amb} = 25 \text{ °C}$ $V_{CE} = -10 \text{ V}; I_{C} = -150 \text{ mA}; \text{ pulsed}; t_{p} \leq 300 \text{ µs}; \delta \leq 0.02; T_{amb} = 25 \text{ °C}$ $V_{CE} = -10 \text{ V}; I_{C} = -500 \text{ mA}; \text{ pulsed}; t_{p} \leq 300 \text{ µs}; \delta \leq 0.02; T_{amb} = 25 \text{ °C}$ collector-emitter $I_{C} = -500 \text{ mA}; I_{B} = -0.5 \text{ mA};$ $T_{amb} = 25 \text{ °C}$ lose-emitter saturation voltage $I_{C} = -500 \text{ mA}; I_{B} = -0.5 \text{ mA}; T_{j} = 150 \text{ °C}$ base-emitter saturation voltage $I_{C} = -500 \text{ mA}; I_{B} = -0.5 \text{ mA};$ $T_{amb} = 25 \text{ °C}$ transition frequency $V_{CE} = -5 \text{ V}; I_{C} = -500 \text{ mA}; f = 100 \text{ MHz};$ $T_{amb} = 25 \text{ °C}$ s (between 10% and 90% levels) turn-on time $I_{Bon} = -0.5 \text{ mA}; I_{Boff} = 0.5 \text{ mA}; I_{Con} = 500 \text{ mA}; T_{Con} = 25 \text{ °C}$	current collector-emitter cut-off current $V_{CE} = -45 \text{ V}; V_{BE} = 0 \text{ V}; T_{amb} = 25 ^{\circ}\text{C}$ - Current $V_{CE} = -10 \text{ V}; I_{C} = -150 \text{ mA}; \text{ pulsed}; t_{p} \le 300 \text{ µs}; \delta \le 0.02; T_{amb} = 25 ^{\circ}\text{C}$ $V_{CE} = -10 \text{ V}; I_{C} = -500 \text{ mA}; \text{ pulsed}; t_{p} \le 300 \text{ µs}; \delta \le 0.02; T_{amb} = 25 ^{\circ}\text{C}$ $V_{CE} = -10 \text{ V}; I_{C} = -500 \text{ mA}; \text{ pulsed}; t_{p} \le 300 \text{ µs}; \delta \le 0.02; T_{amb} = 25 ^{\circ}\text{C}$ $V_{CE} = -500 \text{ mA}; I_{B} = -0.5 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$ $V_{CE} = -500 \text{ mA}; I_{B} = -0.5 \text{ mA}; T_{J} = 150 ^{\circ}\text{C}$ - Dase-emitter saturation $V_{CE} = -500 \text{ mA}; I_{B} = -0.5 \text{ mA}; T_{J} = 150 ^{\circ}\text{C}$ - Dase-emitter saturation $V_{CE} = -500 \text{ mA}; I_{B} = -0.5 \text{ mA}; T_{J} = 150 ^{\circ}\text{C}$ - Transition frequency $V_{CE} = -5 \text{ V}; I_{C} = -500 \text{ mA}; f = 100 \text{ MHz}; T_{J} = 25 ^{\circ}\text{C}$ (between 10% and 90% levels)	current collector-emitter cut-off current $V_{CE} = -45 \text{ V}; V_{BE} = 0 \text{ V}; T_{amb} = 25 ^{\circ}\text{C}$	current collector-emitter cut-off current $V_{CE} = -45 \text{ V}; V_{BE} = 0 \text{ V}; T_{amb} = 25 ^{\circ}\text{C}$ 50 current $V_{CE} = -10 \text{ V}; I_{C} = -150 \text{ mA}; \text{ pulsed}; t_{p} \le 300 \text{ µs}; \delta \le 0.02; T_{amb} = 25 ^{\circ}\text{C}$ $V_{CE} = -10 \text{ V}; I_{C} = -500 \text{ mA}; \text{ pulsed}; t_{p} \le 300 \text{ µs}; \delta \le 0.02; T_{amb} = 25 ^{\circ}\text{C}$ $V_{CE} = -10 \text{ V}; I_{C} = -500 \text{ mA}; \text{ pulsed}; t_{p} \le 300 \text{ µs}; \delta \le 0.02; T_{amb} = 25 ^{\circ}\text{C}$ $V_{CE} = -10 \text{ V}; I_{C} = -500 \text{ mA}; I_{B} = -0.5 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$ $V_{CE} = -500 \text{ mA}; I_{B} = -0.5 \text{ mA}; T_{f} = 150 ^{\circ}\text{C}$ 1.3 base-emitter saturation $V_{CE} = -500 \text{ mA}; I_{B} = -0.5 \text{ mA}; T_{f} = 150 ^{\circ}\text{C}$ 1.3 base-emitter saturation $V_{CE} = -500 \text{ mA}; I_{B} = -0.5 \text{ mA}; T_{f} = 100 \text{ MHz}; T_{f} = 100 \text$

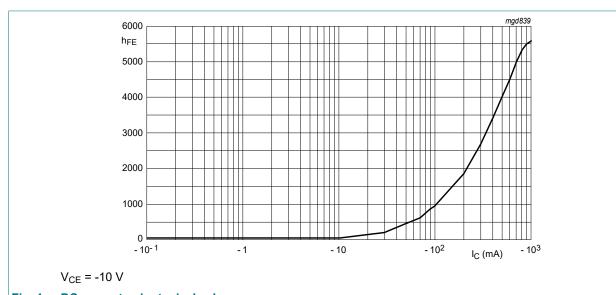
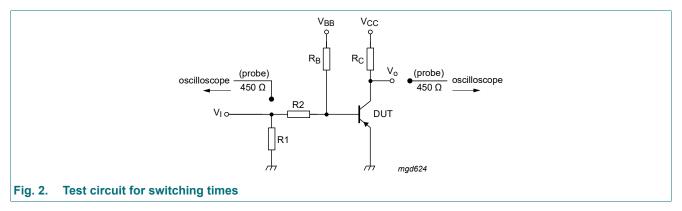


Fig. 1. DC current gain; typical values

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11. Test information

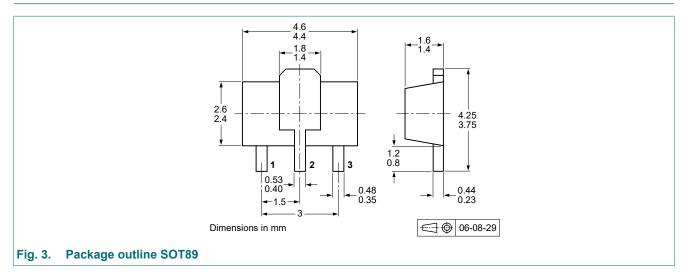


 V_i = -10 V; T = 200 μs; tp = 6 μs; t_r = t_f ≤ 3 ns R1 = 56 Ω; R2 = 10 kΩ; R_B = 10 kΩ; R_C = 18 Ω V_{BB} = 1.8 V; V_{CC} = -10.7 V Oscilloscope: input impedance Z_i = 50 Ω

Quality information

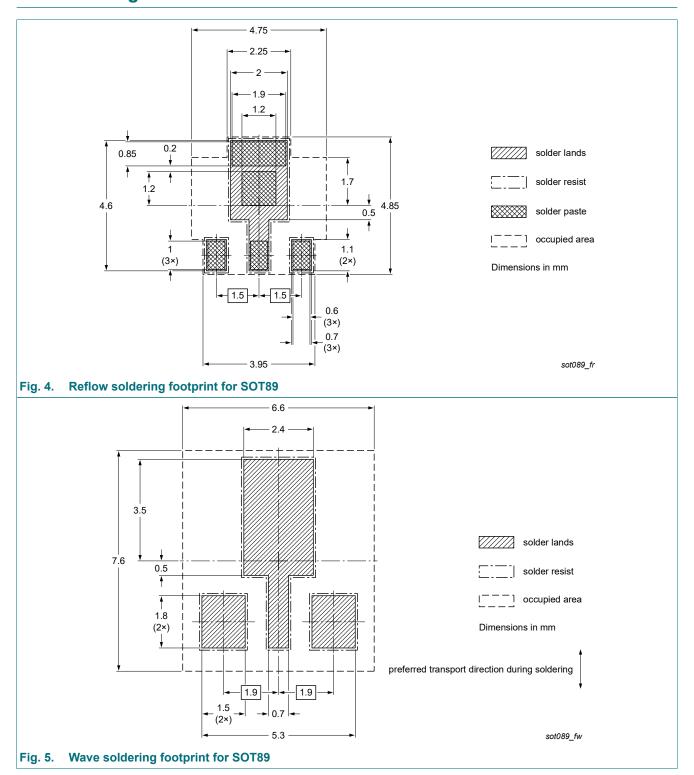
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline



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13. Soldering



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14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BST60-Q v.1	20231027	Product data sheet	-	-

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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